

Docket No.: 061352-0122

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	Customer Number: 20277
Norishige NANAI, et al.	:	Confirmation Number: Not Yet Assigned
Application No.: 10/564,755	:	Group Art Unit: Not Yet Assigned
Filed: January 17, 2006	:	Examiner: Not yet assigned
For: FIELD EFFECT TRANSISTOR AND METHOD OF FABRICATING THE SAME		

INFORMATION DISCLOSURE STATEMENT

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

The relevance of each reference cited on the attached form PTO-1449 is discussed in the present specification.

10/564,755

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

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Date: January 8, 2007

**Please recognize our Customer No. 20277
as our correspondence address.**

INFORMATION DISCLOSURE CITATION IN AN APPLICATION							
				ATTY. DOCKET NO. 061352-0122			
				SERIAL NO. 10/564,755			
(PTO-1449)				APPLICANT Norishige NANAI, et al.			
				FILING DATE January 17, 2006	GROUP Not Yet Assigned		
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code ₂ (<i>if known</i>)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
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FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes -Number + -Kind Codes (<i>if known</i>)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation Yes No	
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
CN		AVOURIS, "Carbon nanotube electronics," Chemical Physics, 2002, pp. 429-445, 281, Elsevier Science B.V.					
CN		ROSENBLATT, et al., "High Performance Electrolyte Gated Carbon Nanotube Transistors," Nano Letters, 2002, pp. 869-872, Vol. 2, No. 8, American Chemical Society.					
CN		KAWASE, et al., "Polymer Semiconductor Active-Matrix Backplane Fabricated by Ink-Jet Technique," IDW, 2002, pp. 219-222, AMD2/EP1-1.					
EXAMINER / Cuong Q Nguyen/				DATE CONSIDERED 03-24-10			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.